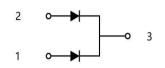


# **Fast Recovery Diode Module**

Symbol	Value	Unit	
$V_R$	400	V	
<b>I</b> FAV	300	Amp	





#### **Features**

- Ultra-fast reverse recovery time
- Soft reverse recovery characteristics
- Low reverse recovery loss
- High system power density

### **Applications**

- Inversion welder
- Power factor correction(PFC)circuit
- Plating power supply
- Ultrasonic cleaner and welder
- Converter & chopper

#### **Maximum Ratings**

Symbol	Item	Conditions	Values	Unit	
VR	Maximum D.C. Reverse Voltage		400	V	
VRRM	Maximum Repetitive Reverse Voltage		400		
IFAV	Average Forward Current	Rectangular, d=0.5, Tc=102℃, Per Leg	150		
		Rectangular , d=0.5 ,	200	Α	
		Tc=102℃, Per Module	300		
IFRMS	RMS Forward Current	Tc=102℃, Per Leg	210	Α	
IFSM	Non-Repetitive Peak Surge Current	Tj = $25^{\circ}$ C, t = $50$ Hz( $10$ ms), VR = $0$ V, Per Leg	2250	А	
ı²t	Circuit Fusing Consideration	t = 10ms Tj =25℃	25310	A <sup>2</sup> s	
Ptot	Total Power Dissipation	Tj =25℃	625	W	
Tj	Operating Junction Temperature		-40 to +150	$^{\circ}$	
Tstg	Storage Temperature		-40 to +125	$^{\circ}$	
Mt	Mounting Torque	To Terminals(M6)	5±15%	NI	
Ms	Mounting Torque	To Heatsink(M6)	5±15%	N·m	
Weight	Module (Approximately)		65	g	

#### **Thermal Characteristics**

Symbol	Item	Conditions	Values	Unit
Rth(j-c)	Thermal Impedance, Max	Junction to Case(Per Leg)	0.20	°C/W

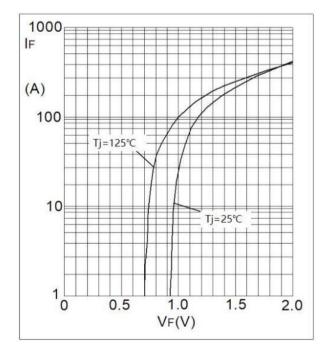
www.hypersemi.com.cn - 1 -

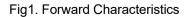


#### **Electrical Characteristics**

Symbol	Item	Conditions	Values			
			Min.	Тур.	Max.	Unit
V <sub>FM</sub>	Forward Voltage Drop Per Leg, Max	Tj=25℃ , I <sub>F</sub> =150A	_	-	1.3	V
	Repetitive Peak Reverse Current	$T_j = 25^{\circ}C$ $V_R = V_{RRM}$	_	_	0.2	
I <sub>RRM</sub>	Danilan May	$T_j = 150^{\circ}\text{C V}_R = V_{RRM}$	_	-	5	mA
t <sub>rr</sub>	Typical Reverse Recovery Time Per Leg	$I_F = 0.5A$ , $I_R = -1A$ , $IRR = -0.25A$	_	90	_	ns
t <sub>rr</sub>	Reverse Recovery Time	IF= 150A,VR=200V, diF/dt=-200A/ μs, Tj = 25°C	_	83	_	ns
<b>I</b> RM	Maximum Reverse Recovery Current	IF=150A,VR=200V, diF/dt=-200A/ μs, Tj =125°C	_	9.5	_	Α
t <sub>rr</sub>	Reverse Recovery Time	T <sub>j</sub> = 125°C		145	_	ns
<b>I</b> RM	Maximum Reverse Recovery Current	T <sub>j</sub> = 125°C	-	16	_	Α
V <sub>T0</sub>	Threshold Voltage, for power loss calculation only	IF=0.5A, IR=-1A, IRR=-0.25A		0.7		V
ľΤ	Slope Resistance, for power loss calculation only	IF=150A,VR=200V, diF/dt=-200A/ $\mu$ s, Tj =25°C		3.0		mΩ

## **Characteristics Diagram**





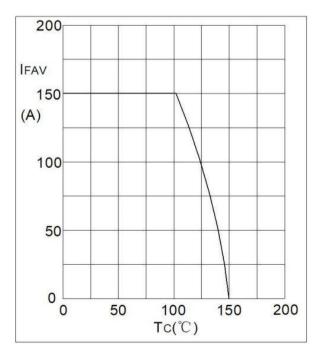


Fig2. Forward Current Derating Curve

www.hypersemi.com.cn -2-

# HF8MURH300N4X100 Fast Recovery Diode Module

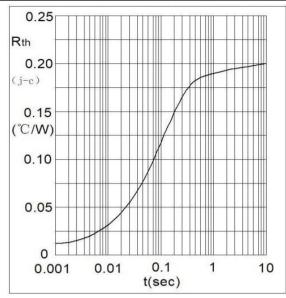


Fig3. Transient Thermal Impedance

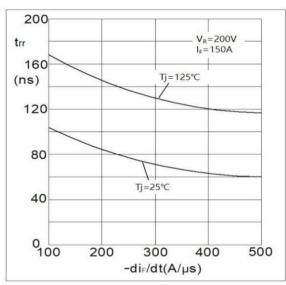
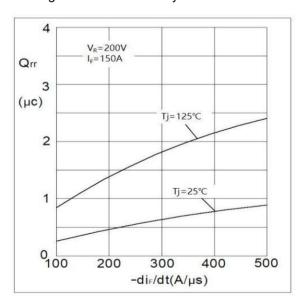


Fig5. Reverse Recovery Time VS diF/dt



2500 IFSM
2000
(A)
1500

1000

500

0
1 5 10 50 100
(Cycle)

Fig4. Max Non-Repetitive Forward Surge Current

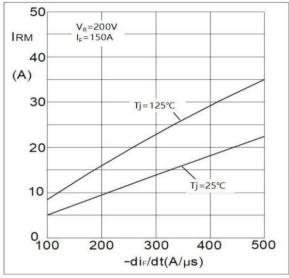


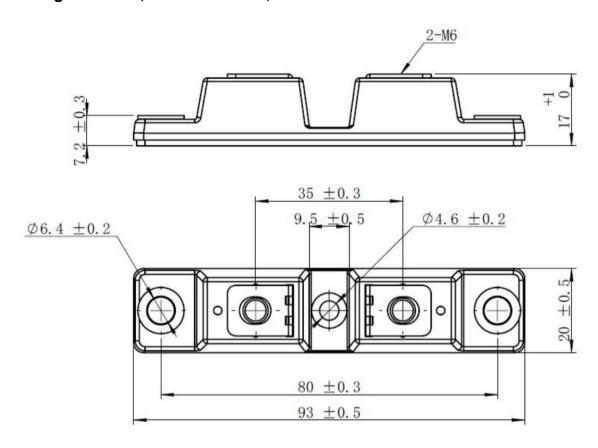
Fig6. Reverse Recovery Current VS diF/dt

Fig7. Reverse Recovery Charge VS diF/dt

www.hypersemi.com.cn - 3 -



#### Package Outlines(Dimensions in mm)



#### \*IMPORTANT INFORMATION AND NOTICE

The specifications of Zhuhai Hypersemi Co., Ltd. products may not be considered as a guarantee or assurance of product characteristics. The specifications describe only the usual characteristics of products expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance, and application adjustments may be necessary. The user of our products is responsible for the safety of their applications embedding our products and must take adequate safety measures to prevent the applications from causing physical injury, fire or other problems if any of our products become faulty. The user is responsible for ensuring that the application design complies with all applicable laws, regulations, norms, and standards. Except as otherwise explicitly approved by Zhuhai Hypersemi Co., Ltd. in a written document signed by authorized representatives, our products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

No representation or warranty is given, and no liability is assumed with respect to the accuracy, completeness, and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. Zhuhai Hypersemi Co., Ltd. does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets, or other intellectual property rights, nor the rights of others. We make no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. Due to technical requirements, our products may contain dangerous substances. For information on the types in question, please contact the nearest sales office. This document supersedes and replaces all information previously supplied and may be superseded by updates. We reserve the right to make changes.

www.hypersemi.com.cn - 4 -